NSN 5961-01-016-8476

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Inclosure Material:
Metal
Overall Length:
0.450 inches
Overall Diameter:
0.875 inches
Mounting Facility Quantity:
2
Electrode Internally-electrically Connected To Case:
Collector
Mounting Method:
Unthreaded hole
Semiconductor Material:
Silicon
Voltage Rating In Volts Per Characteristic:
400.0 breakdown voltage, collector-to-base, emitter open and 400.0 breakdown voltage, collector-to-emitter, base open and 7.0
breakdown voltage, emitter-to-base, collector open
Current Rating Per Characteristic:
Between 2.00 amperes source cutoff current and 10.00 amperes source cutoff current
Power Rating Per Characteristic:
100.0 watts small-signal input power, common-collector
Maximum Operating Tempurature Per Measurement Point:
165.0 degrees celsius junction
Terminal Type And Quantity:
2 pin and 1 case
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
No
Fiig:
A110a0